NSN 5961-01-103-4877

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View Online at https://aerobasegroup.com/nsn/5961-01-103-4877 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 1.550 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter voltage/static/base open and 100.0 breakdown voltage, collector-to-emitter, base open and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 50.00 amperes source cutoff current and 7.50 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector absolute **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0